

## Tuning the charge conductivity and thermoelectric properties of oriented F4TCNQ-P3HT films by controlled dopant intercalation

Viktoriiia Untilova<sup>1\*</sup>, Laure Biniek<sup>1</sup>, Till Biskup<sup>2</sup>, Martin Brinkmann<sup>1\*</sup>

<sup>1</sup> Université de Strasbourg, CNRS, ICS UPR 22, F-67000 Strasbourg, France

<sup>2</sup> Institut für Physikalische Chemie, Albertstraße 21, 79104 Freiburg im Breisgau, Germany

\* [viktoriiia.untilova@ics-cnrs.unistra.fr](mailto:viktoriiia.untilova@ics-cnrs.unistra.fr)

This contribution focuses on the impact of crystallinity, structure and orientation on the doping efficiency and resulting thermoelectric (TE) properties of oriented regioregular poly(3-hexylthiophene) films doped with F4TCNQ.<sup>[1]</sup> We use the rubbing temperature ( $T_R$ ) as a handle to tune the film's structure and investigate by a combination of UV-Vis-NIR spectroscopy, Transmission Electron Microscopy (Electron Diffraction), Electron Spin Resonance (EPR), charge conductivity and thermopower measurements, how the structural variety impacts charge conductivity and TE properties.<sup>[2]</sup>

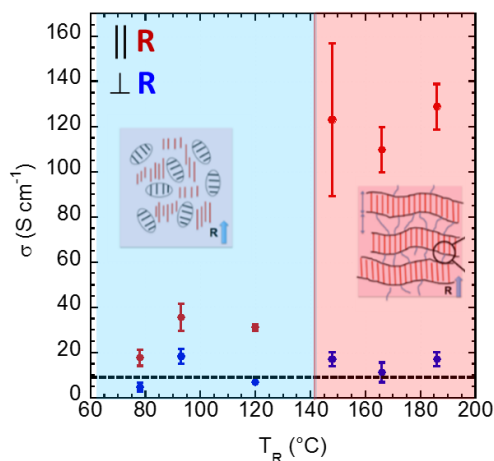


Figure 1: Evolution of the charge conductivity measured along and perpendicular to the rubbing direction  $R$  for P3HT films rubbed at different  $T_R$  and doped with  $F_4TCNQ$

and the orientation distribution of the intercalated dopants. Optimal TE performances are obtained for thin films rubbed at 186°C with conductivities of up to 160 S/cm and power factors of 56  $\mu W m^{-1} K^{-2}$  along the rubbing direction versus a few  $\mu W m^{-1} K^{-2}$  for non-oriented films.

### References

- [1] A. Hamidi-Sakr, L. Biniek, J.-L. Bantignies, D. Maurin, L. Herrmann, N. Leclerc, P. Lévêque, V. Vijayakumar, N. Zimmermann, and M. Brinkmann, *Adv. Funct. Mater.* 1700173 (2017).
- [2] V. Vijayakumar, Y. Zhong, V. Untilova, M. Bahri, L. Herrmann, L. Biniek, N. Leclerc and M. Brinkmann, *Adv. En. Mater.* 1900266 (2019).
- [3] A. Hamidi-Sakr, L. Biniek, S. Fall, M. Brinkmann *Adv. Funct. Mater.* 26, 408–420 (2016).

As a main result, the semi-crystalline structure of aligned P3HT films obtained for  $T_R > 144^\circ C$  shows superior conductivity and TE efficiencies (power factor) as compared to the smectic-like phase ( $50^\circ C \leq T_R \leq 125^\circ C$ ) because of both a higher in-plane orientation and a higher doping level.<sup>[3]</sup> Electron Diffraction on doped oriented films of the smectic-like and the semi-crystalline phases highlight differences in the intercalation mechanism of  $F_4TCNQ$  in the layers of alkyl side chains. We demonstrate the counter-intuitive idea that doping can promote ordering of P3HT backbones along the chain direction within individual  $\pi$ -stacks. Correlations between the order parameter and the anisotropy in charge transport and Seebeck coefficient are revealed. The angular dependence of characteristic polaronic and anionic bands helps quantify the amount